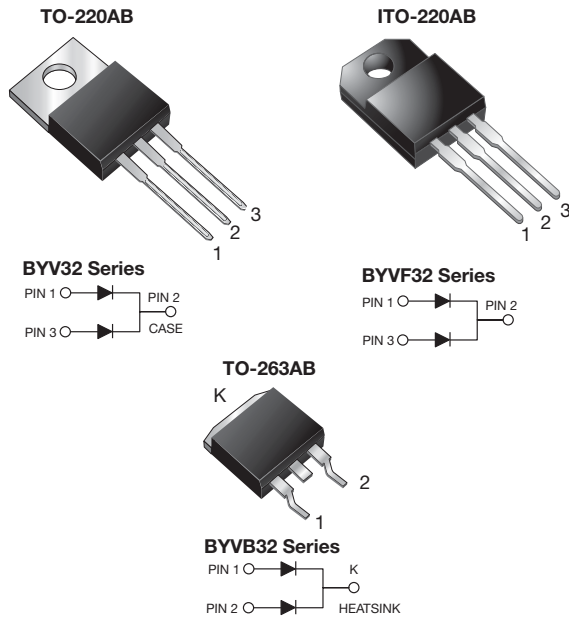


## Dual Common-Cathode Ultrafast Rectifier



### FEATURES

- Power pack
- Glass passivated pallet chip junction
- Ultrafast recovery time
- Low switching losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	18 A
$V_{RRM}$	50 V to 200 V
$I_{FSM}$	150 A
$t_{rr}$	25 ns
$V_F$	0.85 V
$T_J$ max.	150 °C
Package	TO-220AB, ITO-220AB, TO-263AB
Diode variations	Common cathode

### MECHANICAL DATA

**Case:** TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-E3 - RoHS-compliant, commercial grade  
Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs max.

### MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	V
Maximum RMS voltage	$V_{RMS}$	35	70	105	140	V
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	V
Maximum average forward rectified current at $T_C = 125$ °C	$I_{F(AV)}$	18				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	150				A
Operating storage and temperature range	$T_J, T_{STG}$	-65 to +150				°C
Isolation voltage (ITO-220AB only) from terminal to heatsink $t = 1$ min	$V_{AC}$	1500				V



<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	BYV32-50	BYV32-100	BYV32-150	BYV32-200	UNIT
Maximum instantaneous forward voltage per diode	$I_F = 20\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	1.15				V
	$F = 5.0\text{ A}$	$T_J = 100\text{ }^\circ\text{C}$		0.85				
Maximum DC reverse current per diode at rated DC blocking voltage			$I_R$	10				$\mu\text{A}$
				600				
Maximum reverse recovery time per diode	$I_F = 1\text{ A}$ , $V_R = 30\text{ V}$ $di/dt = 100\text{ A}/\mu\text{s}$ , $I_{rr} = 10\% I_{RM}$		$t_{rr}$	25				ns
Typical junction capacitance per diode	4.0 V, 1 MHz		$C_J$	45				pF

**Note**(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25\text{ }^\circ\text{C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BYV	BYVF	BYVB	UNIT
Typical thermal resistance from junction to case per diode	$R_{\theta JC}$	1.6	5.0	1.6	$^\circ\text{C}/\text{W}$

<b>ORDERING INFORMATION</b> (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube
TO-263AB	BYVB32-200-E3/45	1.35	45	50/tube	Tube
TO-263AB	BYVB32-200-E3/81	1.35	81	800/reel	Tape and reel
TO-220AB	BYV32-200HE3/45 <sup>(1)</sup>	1.85	45	50/tube	Tube
ITO-220AB	BYVF32-200HE3/45 <sup>(1)</sup>	1.97	45	50/tube	Tube
TO-263AB	BYVB32-200HE3/45 <sup>(1)</sup>	1.35	45	50/tube	Tube
TO-263AB	BYVB32-200HE3/81 <sup>(1)</sup>	1.35	81	800/reel	Tape and reel

**Note**

(1) AEC-Q101 qualified



RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

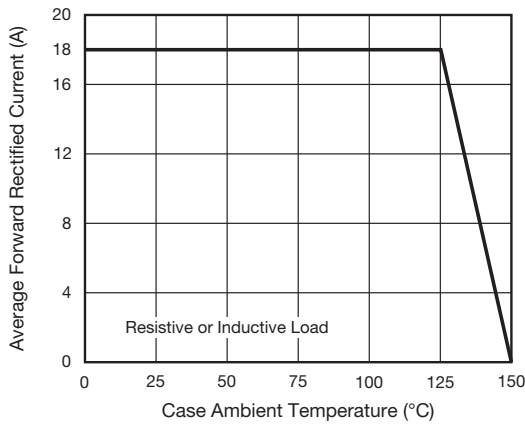


Fig. 1 - Forward Current Derating Curve

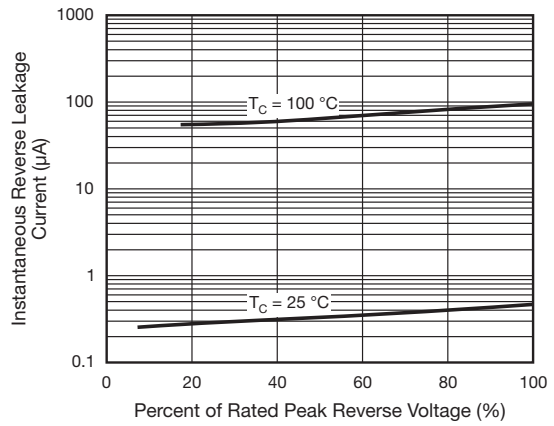


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

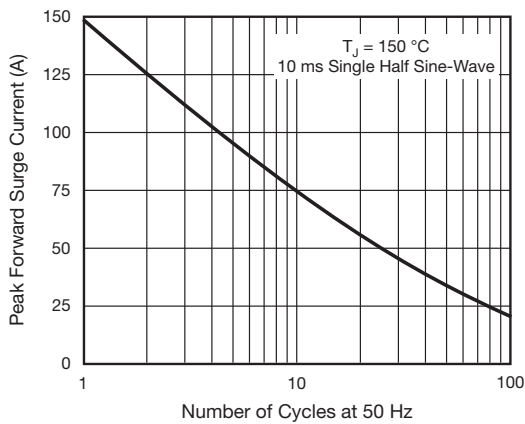


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

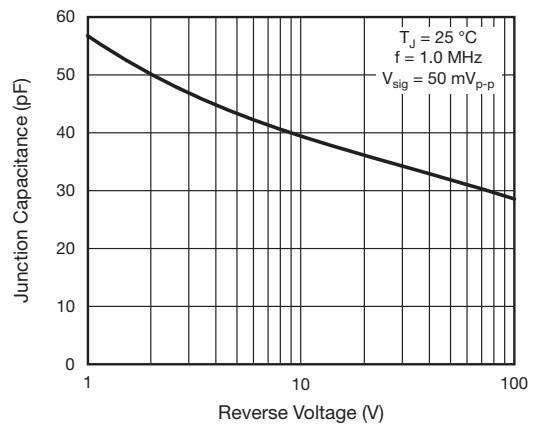


Fig. 5 - Typical Junction Capacitance Per Diode

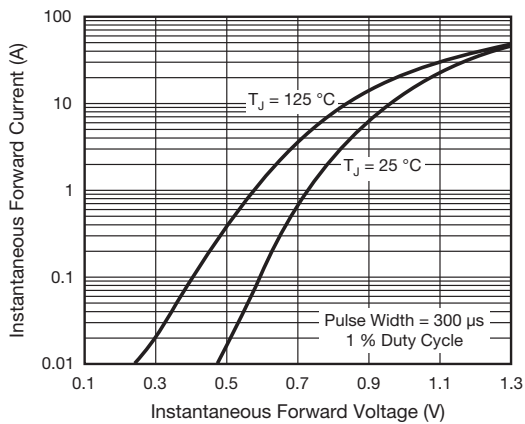
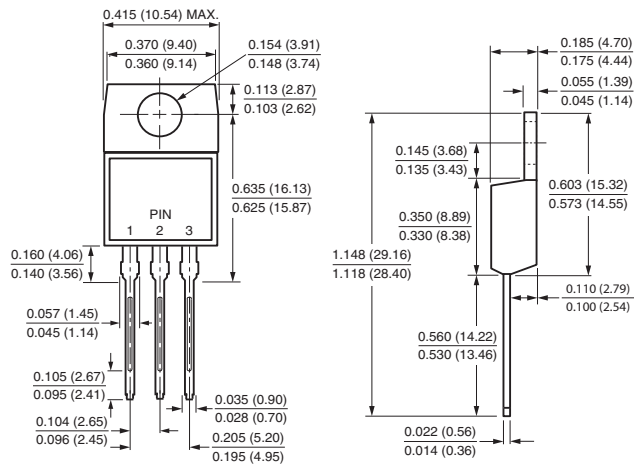


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

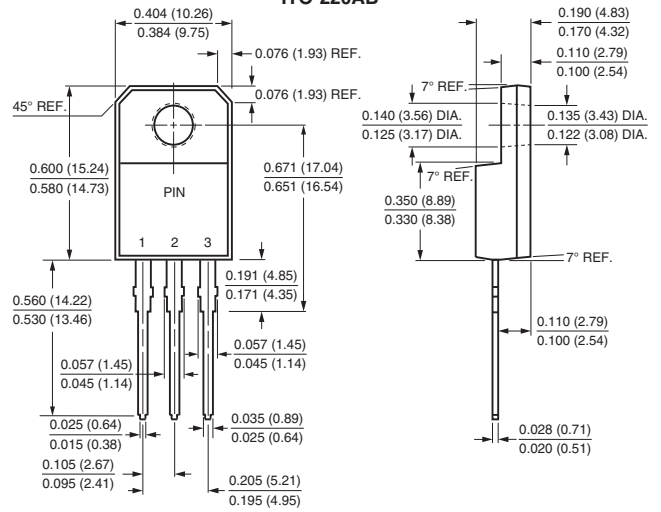


PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

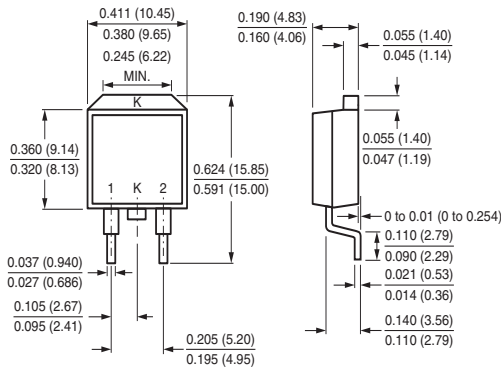
TO-220AB



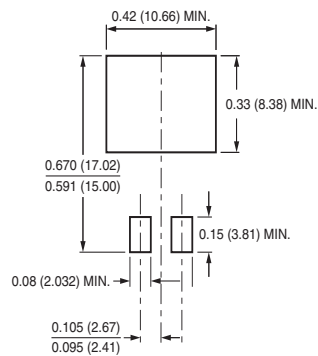
ITO-220AB



TO-263AB



Mounting Pad Layout





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